DISCRETE SEMICONDUCTORS



Product specification

January 1985



HILIPS

Product specification

BLU30/12

UHF power transistor

DESCRIPTION

N-P-N silicon planar epitaxial transistor primarily intended for use in mobile radio transmitters in the 470 MHz communications band.

FEATURES:

- multi-base structure and emitter-ballasting resistors for an optimum temperature profile
- gold metallization ensures excellent reliability
- internal matching to achieve an optimum wideband capability and high power gain

The transistor has a 6-lead flange envelope with a ceramic cap (SOT-119). All leads are isolated from the flange.

QUICK REFERENCE DATA

| Envelope | SOT-119 | | | |
|----------------------------------|----------------|---------------|------|-----|
| Mode of operation | class | class-B; c.w. | | |
| Collector-emitter voltage (d.c.) | V_{CE} | | 12,5 | V |
| Frequency | f | | 470 | MHz |
| Load power | P_L | | 30 | W |
| Power gain | GP | > | 6,0 | dB |
| Collector efficiency | ηc | > | 55 | % |
| Heatsink temperature | T _h | | 25 | °C |

PIN CONFIGURATION



PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | emitter |
| 2 | emitter |
| 3 | base |
| 4 | collector |
| 5 | emitter |
| 6 | emitter |

PRODUCT SAFETY This device incorporates beryllium oxide, the dust of which is toxic. The device is entirely safe provided that the BeO disc is not damaged.

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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| Collector-base voltage (open emitter) | | | | |
|---|-------------------------|--------|-------|----|
| peak value | V _{CBOM} | max. | 36 | V |
| Collector-emitter voltage (open base) | V _{CEO} | max. | 16,5 | V |
| Emitter-base voltage (open collector) | V _{EBO} | max. | 4 | V |
| Collector current | | | | |
| d.c. or average | Ι _C | max. | 6 | А |
| (peak value); f > 1 MHz | I _{CM} | max. | 18 | А |
| Total power dissipation | | | | |
| $f > 1 \text{ MHz}; T_{mb} = 25 ^{\circ}\text{C}$ | P _{tot} (r.f.) | max. | 65 | W |
| Storage temperature | T _{stg} | –65 to | + 150 | °C |
| Operating junction temperature | Тj | max. | 200 | °C |
| | | | | |





THERMAL RESISTANCE

(dissipation = 45 W; T_{mb} = 25 °C)

From junction to mounting base

(r.f. dissipation)

From mounting base to heatsink

 R_{th j-mb(r.f.)}
 max.
 2,45
 K/W

 R_{th mb-h}
 max.
 0,2
 K/W

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| CHARACTERISTICS | | | | |
|---|----------------------|------|------|----|
| $T_j = 25 \text{ °C}$ unless otherwise specified | | | | |
| Collector-base breakdown voltage | | | | |
| I _C = 50 mA; open emitter | V _{(BR)CBO} | > | 36 | V |
| Collector-emitter breakdown voltage | | | | |
| I _C = 100 mA; open base | V _{(BR)CEO} | > | 16,5 | V |
| Emitter-base breakdown voltage | | | | |
| I _E = 10 mA; open collector | V _{(BR)EBO} | > | 4 | V |
| Collector cut-off current | | | | |
| $V_{BE} = 0; V_{CE} = 16 V$ | I _{CES} | < | 22 | mA |
| Second breakdown energy | | | | |
| L = 25 mH; f = 50 Hz; R_{BE} = 10 Ω | E _{SBR} | > | 8 | mJ |
| D.C. current gain | | | | |
| | b | > | 15 | |
| $I_{C} = 4 \text{ A}; V_{CE} = 10 \text{ V}$ | h _{FE} | typ. | 60 | |
| Collector capacitance at $f = 1 \text{ MHz}^{(1)}$ | | | | |
| I _E = i _e = 0; V _{CB} = 12,5 V | C _c | typ. | 85 | pF |
| Feed-back capacitance at $f = 1 \text{ MHz}^{(1)}$ | | | | |
| I _C = 0; V _{CE} = 12,5 V | C _{re} | typ. | 52 | pF |
| Collector-flange capacitance | C _{cf} | typ. | 3 | pF |
| | - | | | - |

Note

1. Device mounted in SOT-119 envelope without inputmatching.





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APPLICATION INFORMATION

| Mode of operation | In narrow-band test circuit; class-B; c.w. | | | |
|-------------------------------------|--|------|------|-----|
| Collector-emitter voltage (d.c.) | V_{CE} | | 12,5 | V |
| Frequency | f | | 470 | MHz |
| Load power | P_L | | 30 | W |
| Power anin | C | > | 6,0 | dB |
| Power gain | G _p | typ. | 7,4 | dB |
| Collector officiency | | > | 55 | % |
| Collector efficiency η _C | typ. | 66 | % | |
| Heatsink temperature | T _h | | 25 | °C |
| | | | | |



List of components:

- C1 = C2 = C7 = C8 = 2 to 9 pF film dielectric trimmer (cat. no. 2222 809 09002)
- C3 = C6 = 3,9 pF ceramic capacitor (500 V)
- C4 = 100 pF feed-through capacitor
- C5 = 100 nF polyester film capacitor
- L1 = stripline (24,0 mm \times 6,7 mm)
- L2 = 10 turns closely wound enamelled Cu-wire (0,4 mm); int. diam. 4 mm
- L3 = 2 turns enamelled Cu-wire (0,6 mm); Ferroxcube tube core, grade 3B5 (cat. no. 4313 020 15170)
- L4 = 12,6 nH; 2,5 turns enamelled Cu-wire (0,7 mm); int. diam. 4 mm; length 3 mm; leads 2 × 5 mm
- L5 = Ferroxcube wideband h.f. choke, grade 3B (cat. no. 4312 020 36642)
- L6 = stripline (28,4 mm \times 6,7 mm)
- R1 = R2 = 10 Ω carbon resistor

L1 and L6 are striplines on a double Cu-clad printed circuit board with P.T.F.E. fibre-glass dielectric ($\epsilon_r = 2,74$); thickness $\frac{1}{16}$ inch.

Component lay-out and printed-circuit board for 470 MHz test circuit are shown in Figs 7 and 8.

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RUGGEDNESS

The device is capable of withstanding a full load mismatch (VSWR = 50; all phases) up to 38 W under the following conditions:

 V_{CE} = 15,5 V; f = 470 MHz; T_{h} = 25 °C; $R_{th\,mb\text{-}h}$ = 0,2 K/W.

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MDA333







ZL 3

2

1

0

(Ω)

class-B operation; $R_{th mb-h} = 0.2$ K/W; typical values.



PACKAGE OUTLINE

Flanged ceramic package; 2 mounting holes; 6 leads



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DEFINITIONS

| Data Sheet Status | | | | |
|---|---|--|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | |
| Product specification | This data sheet contains final product specifications. | | | |
| Limiting values | | | | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | |

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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